RENESAS HD74LVC08

Quad. 2-input AND Gates

REJ03D0344-0300Z (Previous ADE-205-063B (Z)) Rev.3.00 Jul. 22, 2004

Description

The HD74LVC08 has four 2-input AND gates in a 14 pin package. Low voltage and high speed operation is suitable at the battery drive product (note type personal computer) and low power consumption extends the life of a battery for long time operation.

Features

- $V_{CC} = 2.0 \text{ V to } 5.5 \text{ V}$
- All inputs V_{IH} (Max.) = 5.5 V (@V_{CC} = 0 V to 5.5 V)
- Typical V_{OL} ground bounce < 0.8 V (@V_{CC} = 3.3 V, Ta = 25°C)
- Typical V_{OH} undershoot > 2.0 V (@V_{CC} = 3.3 V, Ta = 25°C)
- High output current ± 24 mA (@V_{CC} = 3.0 V to 5.5 V)
- Ordering Information

	-	Package Code	Package Abbreviation	Taping Abbreviation (Quantity)
HD74LVC08FPEL	SOP-14 pin (JEITA)	FP-14DAV	FP	EL (2,000 pcs/reel)
HD74LVC08TELL	TSSOP-14 pin	TTP-14DV	Т	ELL (2,000 pcs/reel)

Note: Please consult the sales office for the above package availability.

Function Table

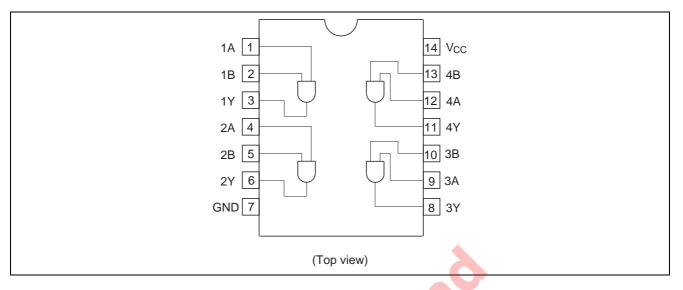
Inputs			
Α	В	Output Y	
L		L	
Н		L	
L	Н	L	
Н	Н	Н	
	-		

H: High level

L: Low level

HD74LVC08

Pin Arrangement



Absolute Maximum Ratings

Symbol	Ratings	Unit	Conditions
Vcc	–0.5 to 6.0	V	
I _{IK}	-50	mA	V _I = -0.5 V
VI	-0.5 to 6.0	V	
Ι _{ΟΚ}	-50	mA	$V_0 = -0.5 V$
	50		$V_{O} = V_{CC}$ +0.5 V
Vo	-0.5 to V _{CC} +0.5	V	
lo	±50	mA	
I _{CC} or I _{GND}	100	mA	
Tstg	-65 to +150	°C	
	V _{CC} I _{IK} V _I I _{OK} V ₀ I ₀ I _{CC} or I _{GND}	$\begin{array}{c c} V_{CC} & -0.5 \text{ to } 6.0 \\ \hline I_{IK} & -50 \\ \hline V_{I} & -0.5 \text{ to } 6.0 \\ \hline I_{OK} & -50 \\ \hline 50 \\ \hline V_{O} & -0.5 \text{ to } V_{CC} + 0.5 \\ \hline I_{O} & \pm 50 \\ \hline I_{CC} \text{ or } I_{GND} & 100 \\ \end{array}$	$\begin{array}{c c c c c c c c c c c c c c c c c c c $

Note: The absolute maximum ratings are values, which must not individually be exceeded, and furthermore, no two of which may be realized at the same time.

Recommended Operating Conditions

Item	Symbol	Ratings	Unit	Conditions
Supply voltage	Vcc	1.5 to 5.5	V	Data retention
		2.0 to 5.5		At operation
Input / Output voltage	VI	0 to 5.5	V	А, В
	Vo	0 to V _{CC}		Y
Operating temperature	Та	-40 to 85	°C	
Output current	I _{OH}	-12	mA	V _{CC} = 2.7 V
		-24 ^{*2}		V _{CC} = 3.0 V to 5.5 V
	IOL	12	mA	V _{CC} = 2.7 V
		24 ^{*2}		V _{CC} = 3.0 V to 5.5 V
Input rise / fall time ^{*1}	t _r , t _f	10	ns/V	

Notes: 1. This item guarantees maximum limit when one input switches.

Waveform: Refer to test circuit of switching characteristics.

2. Duty cycle $\leq 50\%$



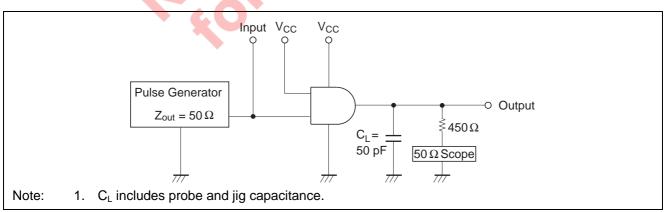
Electrical Characteristics

			Ta = -40 to 85°C				
Item	Symbol	V _{cc} (V)	Min	Max	Unit	Test Conditions	
Input voltage	V _{IH}	2.7 to 3.6	2.0	_	V		
		4.5 to 5.5	V _{CC} ×0.7	_	_		
	V _{IL}	2.7 to 3.6	_	0.8	V		
		4.5 to 5.5	_	V _{CC} ×0.3	_		
Output voltage	V _{OH}	2.7 to 5.5	V _{CC} -0.2		V	I _{OH} = -100 μA	
		2.7	2.2	_	_	$I_{OH} = -12 \text{ mA}$	
		3.0	2.4	_	_	$I_{OH} = -12 \text{ mA}$	
		3.0	2.0	_	_	$I_{OH} = -24 \text{ mA}$	
		4.5	3.8	_	_	$I_{OH} = -24 \text{ mA}$	
	V _{OL}	2.7 to 5.5	_	0.2	V	I _{OL} = 100 μA	
		2.7	_	0.4	_	I _{OL} = 12 mA	
		3.0	_	0.55	_	I _{OL} = 24 mA	
		4.5	_	0.55	_	$l_{OL} = 24 \text{ mA}$	
Input current	I _{IN}	0 to 5.5	_	±5.0	μA	$V_{IN} = 5.5 \text{ V or GND}$	
Quiescent supply current	I _{CC}	5.5	_	20	μA	$V_{IN} = V_{CC}$ or GND	
	ΔI_{CC}	3.0 to 3.6	_	500	μA	V_{IN} = one input at (V _{CC} -0.6)V, other inputs at V _{CC} or GND	

Switching Characteristics

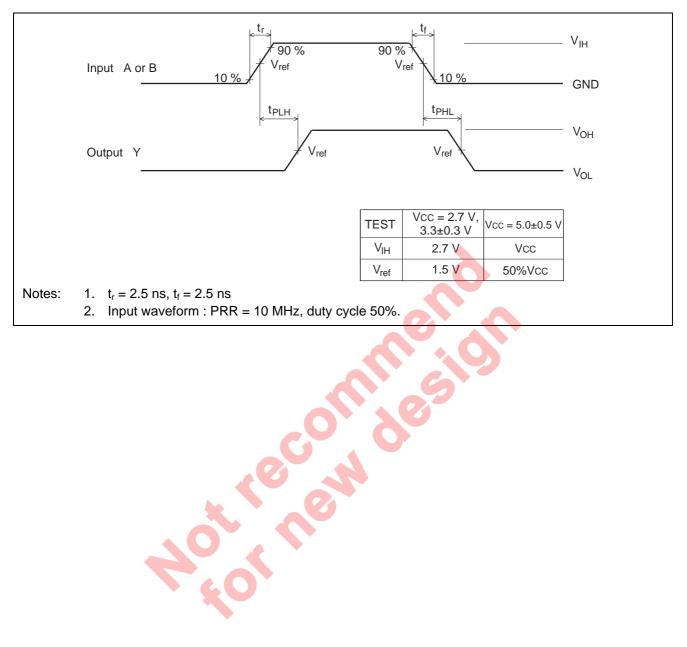
			Ta = -40 to 85°C				From	То
Item	Symbol	V _{cc} (V)	Min	Тур	Max	Unit	(Input)	(Output)
Propagation delay time	t _{PLH}	2.7	6	4.5	7.0	ns	A or B	Y
	t _{PHL}	3.3±0.3	1.5	3.5	6.0			
		5.0±0.5	-	2.5	5.0			
Input capacitance	CIN	2.7	-0	3.0	—	pF		
Output capacitance	Co	2.7		15.0	—	рF		

Test Circuit



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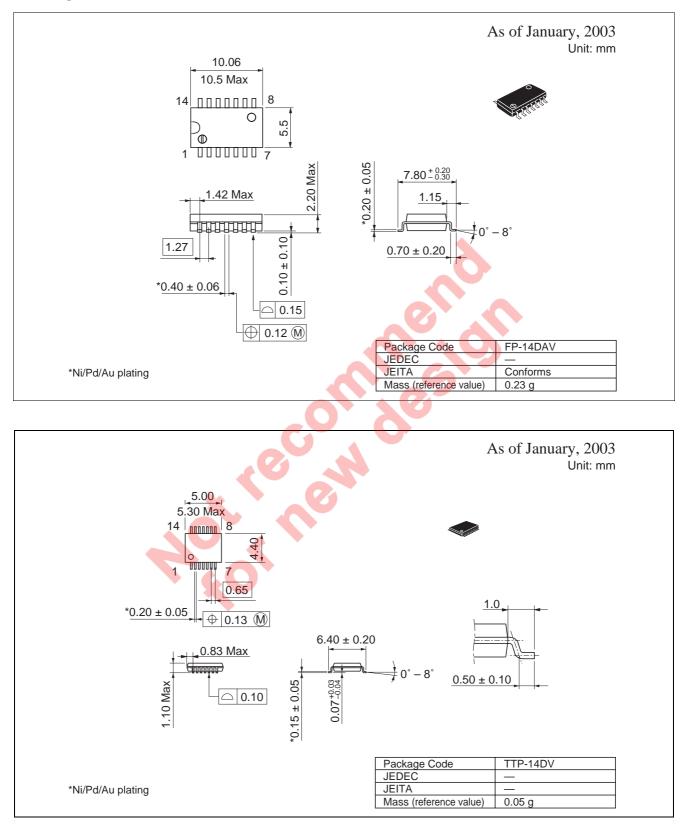
Waveforms



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Package Dimensions





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Renesas Technology Europe Limited. Dukes Meadow, Millboard Road, Bourne End, Buckinghamshire, SL8 5FH, United Kingdom Tel: <44> (1628) 585 100, Fax: <44> (1628) 585 900

Renesas Technology Europe GmbH Dornacher Str. 3, D-85622 Feldkirchen, Germany Tel: <49> (89) 380 70 0, Fax: <49> (89) 929 30 11

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